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Dual J-K Flip-Flops (with Preset and Clear)

RENESAS

ADE-205-423 (Z) 1st. Edition Sep. 2000

Description

Each flip-flop has independent J, K, preset, clear, and clock inputs and Q and \overline{Q} outputs. This device is edge sensitive to the clock input and change state on the negative going transition of the clock pulse. Clear and preset are independent of the clock and accomplished by a low logic level on the corresponding input.

Features

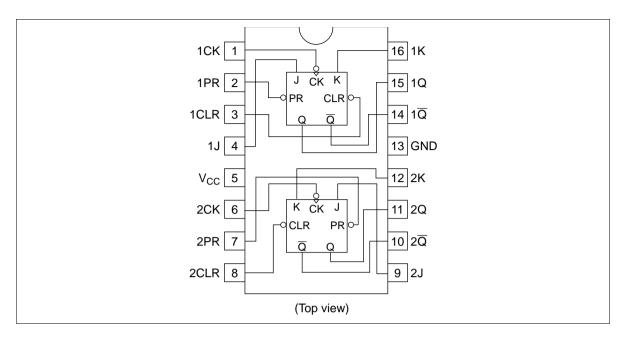
- High Speed Operation: t_{pd} (Clock to Q) = 21 ns typ (C_L = 50 pF)
- High Output Current: Fanout of 10 LSTTL Loads
- Wide Operating Voltage: $V_{CC} = 2 \text{ to } 6 \text{ V}$
- Low Input Current: 1 µA max
- Low Quiescent Supply Current: I_{CC} (static) = 2 μ A max (Ta = 25°C)

Inputs					Outputs	
Preset	Clear	Clock	J	K	Q	Q
L	Н	Х	Х	Х	Н	L
Н	L	Х	Х	Х	L	Н
L	L	Х	Х	Х	H* ¹	H* ¹
Н	Н		L	L	No chang	e
Н	Н		L	Н	L	Н
Н	Н		Н	L	Н	L
Н	Н		Н	Н	Toggle	
Н	Н	L	Х	Х	No chang	e
Н	Н	Н	Х	Х	No chang	e
Н	Н		Х	Х	No chang	e

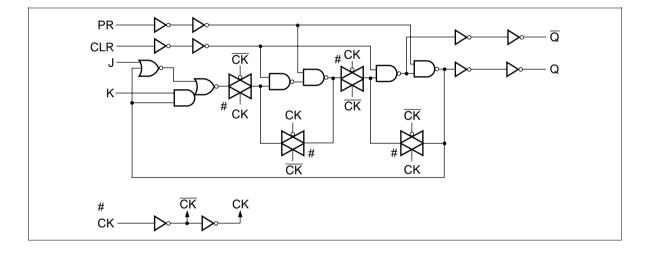
Function Table

Note: 1. Q and \overline{Q} will remain HIGH as long as Preset and Clear are Low, but Q and \overline{Q} are unpredictable, if Preset and Clear go HIGH simultaneously.

Pin Arrangement



Block Diagram (1//2)



DC Characteristics

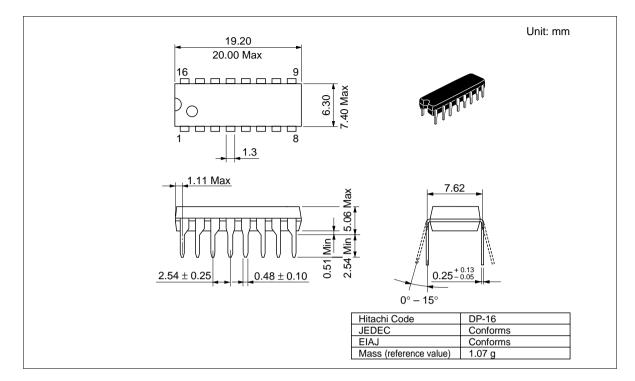
			Ta =	: 25°C		Ta = - +85°C	–40 to C			
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Min	Max	Unit	Test Condition	ns
Input voltage	V _{IH}	2.0	1.5	_	_	1.5	_	V		
		4.5	3.15	—	—	3.15	—			
		6.0	4.2	—	—	4.2	—	_		
	V _{IL}	2.0	_		0.5	—	0.5	V		
		4.5			1.35	_	1.35	_		
		6.0	_		1.8	—	1.8	_		
Output voltage	V _{OH}	2.0	1.9	2.0		1.9	—	V	$Vin = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -20 \ \mu A$
		4.5	4.4	4.5	—	4.4	—	_		
		6.0	5.9	6.0	—	5.9	—	_		
		4.5	4.18		—	4.13	—	_		$I_{OH} = -4 \text{ mA}$
		6.0	5.68		—	5.63	—	_		I _{OH} = -5.2 mA
	V _{OL}	2.0	_	0.0	0.1	—	0.1	V	$Vin = V_{IH} \text{ or } V_{IL}$	$I_{oL} = 20 \ \mu A$
		4.5	_	0.0	0.1	—	0.1	_		
		6.0	—	0.0	0.1	—	0.1			
		4.5	—	—	0.26	—	0.33	_		$I_{OL} = 4 \text{ mA}$
		6.0	_	_	0.26	—	0.33	_		I _{oL} = 5.2 mA
Input current	lin	6.0	_	_	±0.1	_	±1.0	μA	Vin = V _{cc} or GN	ND
Quiescent supply current	I _{cc}	6.0		—	2.0	—	20	μA	Vin = V _{cc} or GN	ND, lout = $0 \mu A$

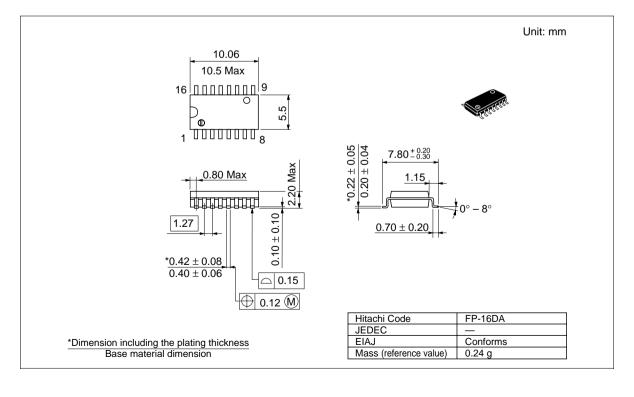


AC Characteristics ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

			Ta =	: 25°C)	Ta = - +85°0	–40 to C		
Item	Symbol	V _{cc} (V)	Min	Тур	Мах	Min	Мах	Unit	Test Conditions
Maximum clock	f _{max}	2.0	_	_	6	_	5	MHz	
frequency		4.5	_	—	30	_	24	-	
		6.0		_	35	_	28	-	
Propagation delay	t _{PLH}	2.0		_	150	_	190	ns	Clock to Q or \overline{Q}
time	t _{PHL}	4.5		21	30	_	38	_	
		6.0	_	_	26	—	33	-	
		2.0		_	140	—	175	-	Clear to Q or \overline{Q}
		4.5		17	28	_	35	-	
		6.0	_	—	24	—	30	-	
		2.0		_	140	_	175	-	Preset to Q or \overline{Q}
		4.5	_	19	28	_	35	-	
		6.0		_	24	_	30	-	
Pulse width	t _w	2.0	80	_	_	100	_	ns	Preset, Clear, Clock
		4.5	16	6	_	20		-	
		6.0	14	_	_	17	_	-	
Setup time	t _{su}	2.0	100	_	_	125	_	ns	J or K to Clock
		4.5	20	4	_	25		-	
		6.0	17	_	_	21	_	-	
Hold time	t _h	2.0	0	_	_	0	_	ns	Clock to J or K
		4.5	0	-3	_	0		-	
		6.0	0	_	_	0	_	-	
Removal time	t _{rem}	2.0	100			125	_	ns	Preset or Clear to Clock
		4.5	20	-2	_	25	_	-	
		6.0	17	_	_	21	_	-	
Output rise/fall	t _{TLH}	2.0			75	—	95	ns	
time	t _{THL}	4.5		5	15	_	19	-	
		6.0		_	13	_	16	-	
Input capacitance	Cin		_	5	10	_	10	pF	

Package Dimensions





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